

HA-2541

40MHz, Fast Settling, Unity Gain Stable, Operational Amplifier

November 1996

Fosturae

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Unity Gain Bandwidth 408	ЛHz
• High Slew Rate	//μ s
• Low Offset Voltage0.8	m۷
• Fast Settling Time (0.1%)	0ns
Power Bandwidth48	ЛHz
Output Voltage Swing (Min)	10V

- . Unity Gain Stability
- · Monolithic Bipolar Dielectric Isolation Construction

Applications

- · Pulse and Video Amplifiers
- · Wideband Amplifiers
- · High Speed Sample-Hold Circuits
- · Fast, Precise D/A Converters
- · High Speed A/D Input Buffer

For a lower power version of this product, please see the HA-2841 data sheet.

Description

The HA-2541 is the first unity gain stable monolithic operational amplifier to achieve 40MHz unity gain bandwidth. A major addition to the Harris series of high speed, wideband op amps, the HA-2541 is designed for video and pulse applications requiring stable amplifier response at low closed loop gains.

The uniqueness of the HA-2541 is that its slew rate and bandwidth characteristics are specified at unity gain. Historically, high slew rate, wide bandwidth and unity gain stability have been incompatible features for a monolithic operational amplifier. But features such as 250V/µs slew rate and 40MHz unity gain bandwidth clearly show that this is not the case for the HA-2541. These features, along with 90ns settling time to 0.1%, make this product an excellent choice for high speed data acquisition systems.

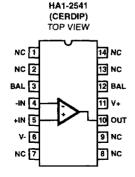
MIL-STD-883 product and data sheets are available upon request, Harris AnswerFAX (407-724-7800) document #3698.

For further application suggestions on the HA-2541, please refer to Application Note AN550 (Using the HA-2541), and Application Note AN556 (Thermal Safe Operating Areas for High Current Operational Amplifiers), Harris AnswerFAX (407-724-7800) document #9550 and 9556. Also see 'Applications' in this data sheet.

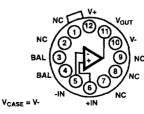
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HA1-2541-2	-55 to 125	14 Ld CERDIP	F14.3
HA1-2541-5	0 to 75	14 Ld CERDIP	F14.3
HA2-2541-2	-55 to 125	12 Pin Metal Can	T12.C
HA2-2541-5	0 to 75	12 Pin Metal Can	T12.C

Pinouts



HA2-2541 (METAL CAN) TOP VIEW



Absolute Maximum Ratings

Voltage Between V+ and V- Terminals 35V Differential Input Voltage 6V Peak Output Current 50mA Continuous Output Current 28mA_{RMS}

Thermal Information

Thermal Resistance (Typical, Note 2)	θ _{JA} (^c C/W	') θ _{.C} (°C/W)
CERDIP Package	75	20
Can Package	65	34
Maximum Junction Temperature (Note 1)		175°C
Maximum Storage Temperature Range		-65°C to 150°C
Maximum Lead Temperature (Soldering 1)	0s)	300°C

Operating Conditions

Temperature Range		
HA-2541-2	 55°C	to 125°C
HA-2541-5	 0 ^c	C to 75°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied

NOTES:

- 1 Maximum power dissipation with load conditions must be designed to maintain the maximum junction temperature below 175°C. By using Application Note AN556 on Safe Operating Area equations, along with the thermal resistances, proper load conditions can be determined. Heat sinking is recommended above 75°C.
- 2. θ_{JA} is measured with the component mounted on an evaluation PC board in free air

Electrical Specifications $V_{SUPPLY} = \pm 15V$, $R_L = 1k\Omega$, $C_L \le 10pF$, Unless Otherwise Specified

	TEST	TEMP	HA-2541-2 -55°C to 125°C			HA-2541-5 0°C to 75°C			
PARAMETER	CONDITIONS	(°C)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
INPUT CHARACTERISTICS									
Offset Voltage		25		0.8	2		1	2	mV
		Full	-	-	6	-	-	6	mV
Average Offset Voltage Drift		Full		9			9		μV, ^o C
Bias Current		25	•	11	35	-	11	35	μА
		Full	-		50	-	-	50	μА
Average Bias Current Drift		Full		85	-	-	85	-	nA/°C
Offset Current		25	-	1	7	-	1	7	μА
		Full	-		9	-	·	9	μА
Input Resistance		25		100	- 1	-	100	-	kΩ
Input Capacitance		25		1	-		1	-	рF
Common Mode Range		Full	±10	±11	-	±10	±11	-	V
Input Noise Voltage	$f = 1kHz$, $R_g = 0\Omega$	25	-	10	-	•	10		nV/√H
Input Noise Current	$f = 1kHz$, $R_g = 0\Omega$	25	-	4	-		4	-	pA/√H
TRANSFER CHARACTERISTICS							•		
Large Signal Voltage Gain	V _O = ±10V	25	10	16		10	16	-	kV∧
		Full	5	-	-	5	-	-	kV∕V
Common Mode Rejection Ratio	V _{CM} = ±10V	Full	70	90	-	70	90	-	dВ
Minimum Stable Gain		25	- 1	•		1	-	-	V/V
Unity Gain Bandwidth	V _O = 90mV	25	-	40	-	-	40		MHz
OUTPUT CHARACTERISTICS									
Output Voltage Swing	R _L = 1kΩ	Fuli	±10	±11	-	±10	±11	-	٧
Output Current	$R_L = 1k\Omega$	25	±10	±15	-	±10	±15	-	mA
Output Resistance		25	-	2	-	-	2	-	Ω
Full Power Bandwidth (Note 3)	V _P = 10V	25	3	4	·	3	4	-	MHz
Differential Gain	Note 4	25	-	0.1		-	0.1	-	%
Differential Phase	Note 4	25	-	0.2	-	-	0.2	-	Degree

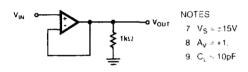
Electrical Specifications	V_{SUPPLY} = ±15V $R_t = 1k\Omega$, $C_t = 10$	OpF. Unless Otherwise Specified	(Continued)
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PARAMETER	TEST	TEMP (°C)	HA-2541-2 -55°C to 125°C			HA-2541-5 0°C to 75°C			
	CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Harmonic Distortion	Note 6	25		<0.01	-		<0.01	-	0.0
TRANSIENT RESPONSE (Note 5)					•				
Rise Time		25	-	4			4		ns
Overshoot		25	-	40			40	-	0,0
Slew Rate		25	200	250	-	200	250	-	V/µs
Settling Time	10V Step To 0.1%	25	-	90	-		90	-	ns
	10V Step To 0.01%	25	-	175	-	-	175	-	ns
POWER REQUIREMENTS								·	
Supply Current		25	-	29	-	-	29	-	mA
		Full			40	-		40	mA
Power Supply Rejection Ratio	V _S = ±5V to ±15V	Full	70	80		70	78	-	dB

NOTES

- β . Full Power Bandwidth guaranteed based on slew rate measurement using: FPBW $_{\odot}$
- 4. Differential Gain and Phase are measured with a 1V differential voltage at 5MHz
- 5 Refer to Test Circuits section of this data sheet
- 6 t. 10kHz. $A_V = 5$; $V_O = 14V_{P,p}$

Test Circuits and Waveforms



SETTLING POINT

VIN VOUT

NOTES

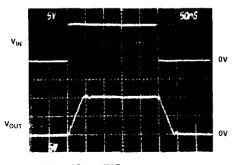
- 10. A_V = -1
- 11. Feedback and summing resistor ratios should be 0.1% matched
- 12 HP5082-2810 clipping diodes recommended

Slew Rate

 $2\pi V_{PEAK}$

13 Tektronix P6201 FET probe used at settling point.

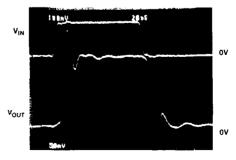
FIGURE 1. TRANSIENT RESPONSE TEST CIRCUIT



Vertical Scale 5V/Div. Horizontal Scale 50ns/Div.

LARGE SIGNAL RESPONSE

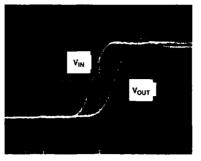
FIGURE 2. SETTLING TIME TEST CIRCUIT



Vertical Scale: $V_{IN} = 100 mV/Div.$, $V_{OUT} = 50 mV/Div.$ Horizontal Scale: 20ns/Div.

SMALL SIGNAL RESPONSE

Test Circuits and Waveforms (Continued)



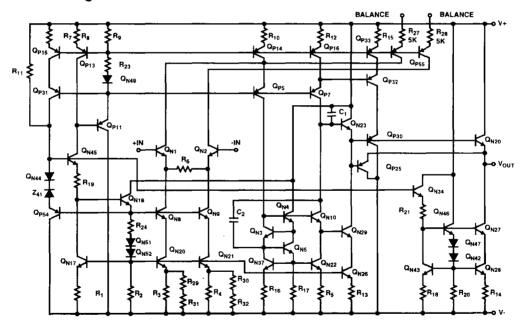
Vertical Scale: 100mV/Div. Horizontal Scale: 5ns/Div.

NOTES:

- 14. $V_S = \pm 15V$, $R_L = 1k\Omega$
- 15. $T_A = 25^{\circ}C$.
- 16. Propagation delay variance is negligible over full temperature range.

PROPAGATION DELAY

Schematic Diagram



Typical Applications (Also see Application Note AN550)

Application 1

High power amplifiers and buffers are in use in a wide variety of applications. Many times the "high power" capability is needed to drive large capacitive loads as well as low value resistive loads. In both cases the final driver stage is usually a power transistor of some type, but because of their inherently low gain, several stages of pre-drivers are often required. The HA-2541, with its 10mA output rating, is powerful enough to drive a power transistor without additional stages of current amplification. This capability is well demonstrated with the high power buffer circuit in Figure 3.

The HA-2541 acts as the pre-driver to the output power transistor. Together, they form a unity gain buffer with the ability to drive three 50Ω coaxial cables in parallel, each with a capacitance of 2000pF. The total combined load is 16.6Ω and 6000pF capacitance.

Application 2

Video

One of the primary uses of the HA-2541 is in the area of video applications. These applications include signal construction, synchronization addition and removal, as well as signal modification. A wide bandwidth device such as the HA-2541 is well suited for use in this class of amplifier. This, however, is a more involved group of applications than ordinary amplifier applications since video signals contain precise DC levels which must be retained.

The addition of a clamping circuit restores DC levels at the output of an amplifier stage. The circuit shown in Figure 4 utilizes the HA-5320 sample and hold amplifier as the DC clamp. Also shown is a 3.57MHz trap in series, which will block the color burst portion of the video signal and allow the DC level to be amplified and restored.

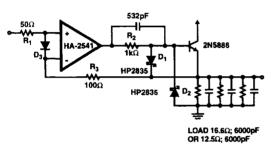


FIGURE 3. DRIVING POWER TRANSISTORS TO GAIN ADDITIONAL CURRENT BOOSTING

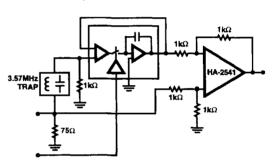
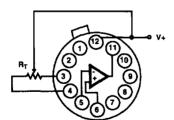
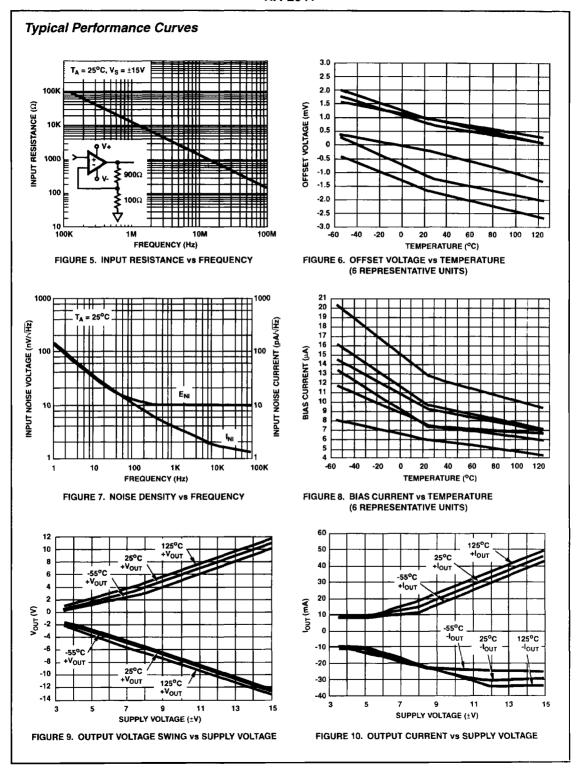


FIGURE 4. VIDEO DC RESTORER

Suggested Offset Voltage Adjustment



NOTE: Tested Offset Adjustment Range is $IV_{OS} + 1mVI$ minimum referred to output. Typical range is $\pm 15mV$ for $R_T = 5k\Omega$.



Typical Performance Curves (Continued)

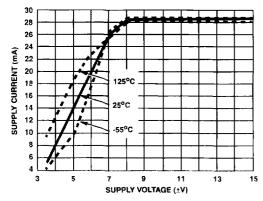


FIGURE 11. SUPPLY CURRENT VS SUPPLY VOLTAGE

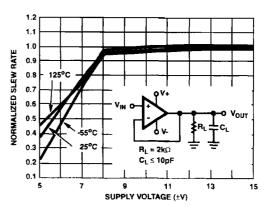


FIGURE 12. SLEW RATE VS SUPPLY VOLTAGE (NORMALIZED WITH V_S = ±15V AT 25°C)

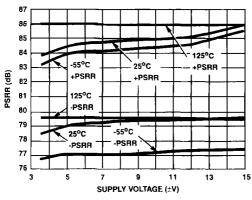


FIGURE 13. PSRR vs SUPPLY VOLTAGE (AVERAGE OF 3 LOTS)

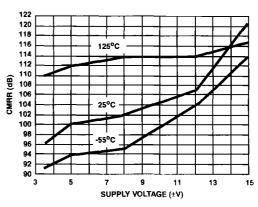


FIGURE 14. CMRR vs SUPPLY VOLTAGE (AVERAGE OF 3 LOTS)

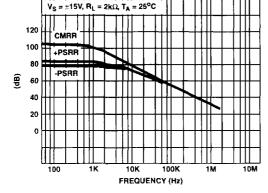


FIGURE 15. REJECTION RATIOS vs FREQUENCY

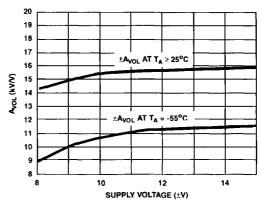
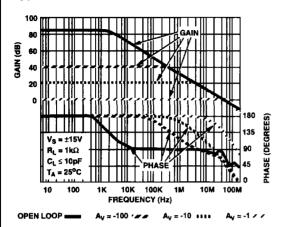


FIGURE 16. OPEN LOOP GAIN VS SUPPLY VOLTAGE (AVERAGE OF 3 LOTS)





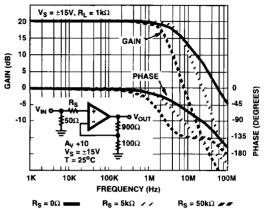


FIGURE 17. GAIN AND PHASE FREQUENCY RESPONSE

FIGURE 18. SMALL SIGNAL BANDWIDTH VS SOURCE RESISTANCE

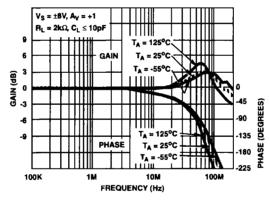


FIGURE 19. CLOSED LOOP FREQUENCY RESPONSE

Die Characteristics

DIE DIMENSIONS:

80 mils x 90 mils x 19 mils 2020µm x 2280µm x 483µm

METALLIZATION:

Type: Al, 1% Cu Thickness: 16kÅ ±2kÅ

PASSIVATION:

Type: Nitride(Si₃N₄) over Silox (SiO₂, 5% Phos.) Silox Thickness: 12kÅ ±2kÅ

Nitride Thickness: 3.5kÅ ±1.5kÅ

SUBSTRATE POTENTIAL (Powered Up):

TRANSISTOR COUNT:

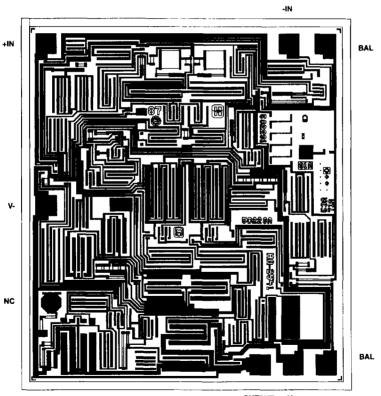
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PROCESS:

Bipolar Dielectric Isolation

Metallization Mask Layout

HA-2541



OUTPUT